



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Applicants: Ting-Wah Wong et al.

Serial No.: 10/081,111

Filed: February 21, 2002

For: Integrated Radio Frequency Circuits

§ Art Unit: 2811

§ Examiner: Ori Nadav

§ Atty Docket: PSS.0029P7US
§

Commissioner for Patents
Washington, D.C. 20231

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REPLY TO PAPER NO. 5

Sir:

In response to the office action mailed December 2, 2002, please amend the above-referenced patent application as follows:

In the Claims:

Please amend claim 1 as follows:

1. (Amended) A method comprising:

forming a metal oxide semiconductor radio frequency circuit element over a triple

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biasing a well of said triple well through a resistor.

Please cancel claim 6 without prejudice.

Please amend claim 20 as follows:

20. (Amended) A method comprising:

forming a first metal oxide semiconductor radio frequency circuit element over a triple well in a substrate;

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biasing a first well of said triple well through a first resistor with a first bias potential;

Date of Deposit: JANUARY 21, 2003
I hereby certify under 37 CFR 1.8(a) that this correspondence is being deposited with the United States Postal Service as First Class Mail with sufficient postage on the date indicated above and is addressed to the Commissioner for Patents, Washington, D.C. 20231.

Ella Sisco